

DATASHEET

4 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER EL817 Series



Features:

- Compliance Halogens Free (Only copper leadframe) (Br < 900 ppm, Cl < 900 ppm, Br+Cl < 1500 ppm)
- Current transfer ratio

(CTR: $50\sim600\%$ at IF = 5mA, VCE = 5V)

- High isolation voltage between input and output (Viso = 5000Vrms)
- Creepage distance > 7.62mm
- Operating temperature up to +110°C
- · Compact small outline package
- •The product itself will remain within RoHS compliant version
- Compliance with EU REACH
- UL and cUL approved(No.E214129)
- VDE approved (No. 132249)
- SEMKO approved
- NEMKO approved
- DEMKO approved
- FIMKO approved
- CQC approved

Description

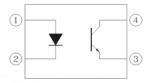
The EL817 series of devices each consist of an infrared emitting diodes, optically coupled to a phototransistor detector.

They are packaged in a 4-pin DIP package and available in wide-lead spacing and SMD option.

Applications

- Programmable controllers
- · System appliances, measuring instruments
- Telecommunication equipments
- Home appliances, such as fan heaters, etc.
- Signal transmission between circuits of different potentials and impedances

Schematic



Pin Configuration

- 1. Anode
- 2. Cathode
- 3. Emitter
- 4. Collector



Absolute Maximum Ratings (Ta=25℃)

	Parameter	Symbol	Rating	Unit
	Forward current	I _F	60	mA
	Peak forward current (1us, pulse)	I _{FP}	1	А
Input	Reverse voltage	V _R	6	V
	Power dissipation	D	100	mW
	Derating factor (above T _a = 100°C)	P_{D}	2.9	mW/°C
Output	Power dissipation		150	mW
	Derating factor (above T _a = 100°C)	P _C	5.8	mW/°C
	Collector current	I _C	50	mA
	Collector-Emitter voltage	V _{CEO}	35	V
	Emitter-Collector voltage	V_{ECO}	6	V
Total Powe	r Dissipation	P _{TOT}	200	mW
Isolation V	oltage* ¹	V _{ISO}	5000	V rms
Operating Temperature		T _{OPR}	-55 to 110	℃
Storage Te	mperature	T _{STG}	-55 to 125	℃
Soldering	Femperature* ²	T _{SOL}	260	℃
				_

Notes:

^{*1} AC for 1 minute, R.H.= $40 \sim 60\%$ R.H. In this test, pins 1, 2 are shorted together, and pins 3, 4 are shorted together.

^{*2} For 10 seconds



Electro-Optical Characteristics (Ta=25°C unless specified otherwise)

Input

Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition
Forward Voltage	V_{F}	-	1.2	1.4	V	I _F = 20mA
Reverse Current	I _R	-	-	10	μA	V _R = 4V
Input capacitance	C _{in}	-	30	250	pF	V = 0, f = 1kHz

Output

Parameter	Symbol	Min	Тур.	Max.	Unit	Condition	
Collector-Emitter dark		_	_	100	nA	$V_{CE} = 20V, I_F = 0mA$	
current	ICEO			100	ПА	V CE - ZO V, IF - OIIIA	
Collector-Emitter	BV_CEO	35	_	-	V	$I_{\rm C} = 0.1 \rm mA$	
breakdown voltage	D A CEO	33	_			IC = 0. IIIIA	
Emitter-Collector	D\/	6			V	I = 0.1mA	
breakdown voltage	BV_{ECO}	O	-	-	V	$I_E = 0.1 \text{mA}$	

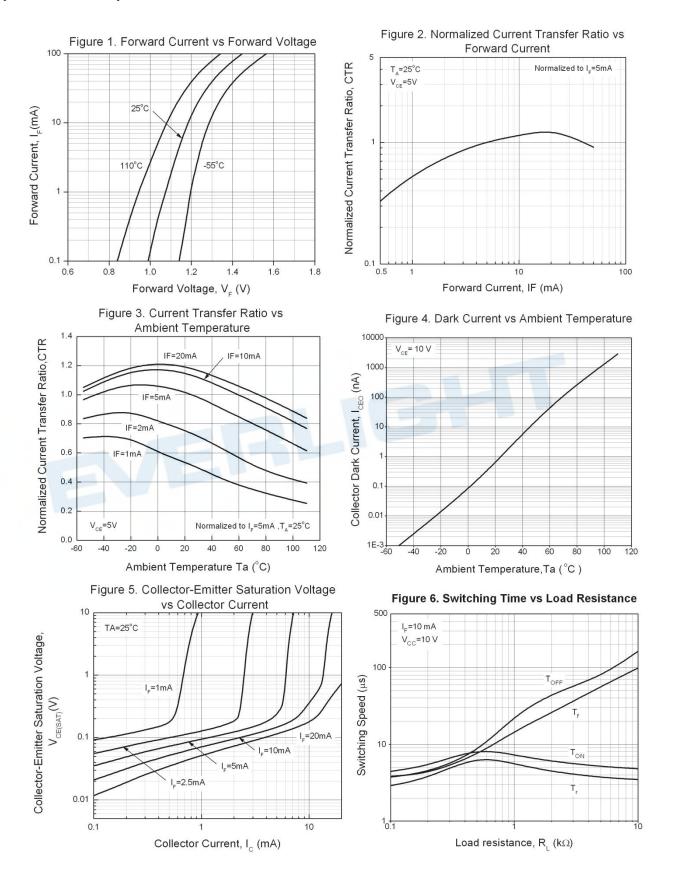
Transfer Characteristics

Parameter		Symbol	Min	Тур.	Max.	Unit	Condition
	EL817	CTR	50		600		I _F = 5mA ,V _{CE} = 5V
	EL817A		80	-	160	- - - % -	
Current	EL817B		130	-	260		
Transfer	EL817C		200	-	400		
ratio	EL817D		300	-	600		
	EL817X		100	-	200		
	EL817Y		150	-	300		
Collector-Emitter saturation voltage		$V_{\text{CE(sat)}}$	-	0.1	0.2	V	I _F = 20mA ,I _C = 1mA
Isolation resistance		R _{IO}	5×10 ¹⁰	-	-	Ω	V _{IO} = 500Vdc, 40~60% R.H.
Floating capacitance		C_{IO}	-	0.6	1.0	рF	$V_{IO} = 0$, $f = 1MHz$
Cut-off frequency		fc	-	80	-	kHz	$V_{CE} = 5V, I_{C} = 2mA$ $R_{L} = 100\Omega, -3dB$
Rise time		t_{r}	-	-	18	μs	$V_{CE} = 2V$, $I_C = 2mA$,
Fall time		t _f	-	-	18	μs	$R_L = 100\Omega$

^{*} Typical values at T_a = 25°C



Typical Electro-Optical Characteristics Curves





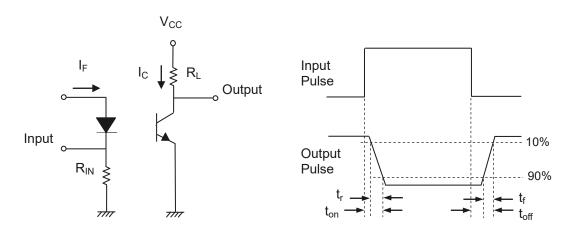


Figure 7. Switching Time Test Circuit & Waveforms





Order Information

Part Number

EL817X(Y)(Z)-FV

Note

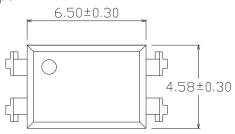
X = Lead form option (S1, S2, M or none)
 Y = CTR Rank (A, B, C, D, X, Y or none)
 Z = Tape and reel option (TU, TD or none)
 F = Lead frame option (F: Iron, None: copper)
 V = VDE safety (optional)

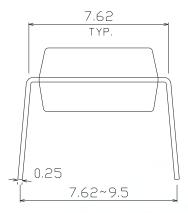
Option	Description	Packing quantity
None	Standard DIP-4	100 units per tube
М	Wide lead bend (0.4 inch spacing)	100 units per tube
S1 (TU)	Surface mount lead form (low profile) + TU tape & reel option	1500 units per reel
S1 (TD)	Surface mount lead form (low profile) + TD tape & reel option	1500 units per reel
S2 (TU)	Surface mount lead form (low profile) + TU tape & reel option	2000 units per reel
S2 (TD)	Surface mount lead form (low profile) + TD tape & reel option	2000 units per reel

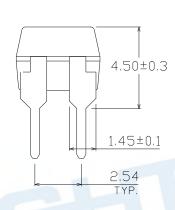


Package Dimension (Dimensions in mm)

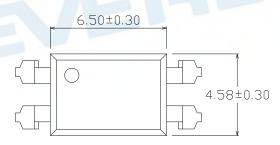
Standard DIP Type

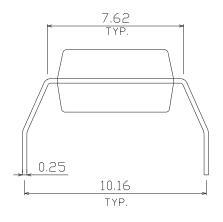


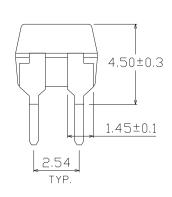




Option M Type

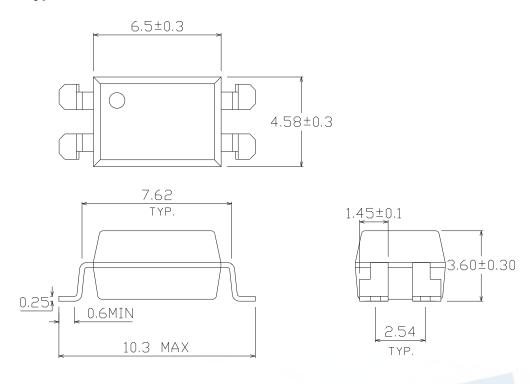




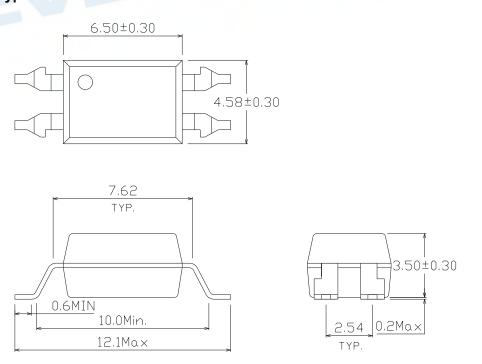




Option S1 Type

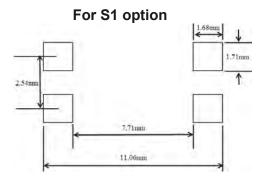


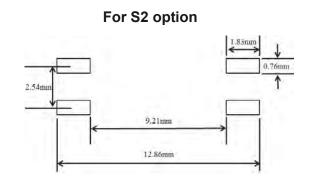
Option S2 Type





Recommended pad layout for surface mount leadform





Notes

Suggested pad dimension is just for reference only. Please modify the pad dimension based on individual need.





Device Marking



Notes

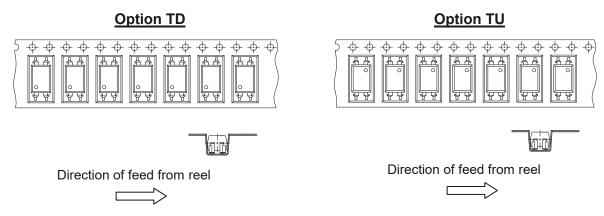
EL	denotes EVERLIGHT
817	denotes Device Number

F denotes Factory Code (G: China and Green part) R denotes CTR Rank (A, B, C, D, X, Y or none)

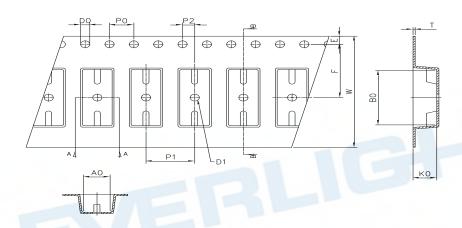
Y denotes 1 digit Year code WW denotes 2 digit Week code V denotes VDE (optional)



Tape & Reel Packing Specifications



Tape dimensions



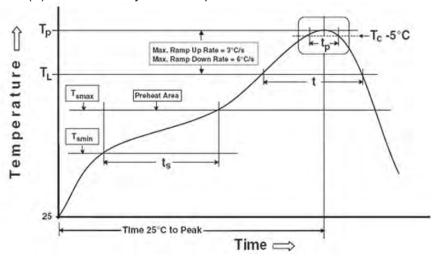
Dimension No.	Ao	Во	Do	D1	E	F
Dimension (mm) S1	4.90±0.1	10.40±0.1	1.5±0.1	1.50±0.1	1.75±0.1	7.50±0.1
Dimension (mm) S2	4.88±0.1	12.55±0.1	1.5±0.1	1.50±0.1	1.75±0.1	11.5±0.1
Dimension No.	Ро	P1	P2	t	w	Ко
Dimension (mm) S1	4.00±0.1	8.00±0.1	2.00±0.1	0.40±0.1	16.00±0.3	4.60±0.1
Dimension (mm) S2	4.00±0.1	8.00±0.1	2.00±0.1	0.40±0.1	24.00±0.3	4.00±0.1



Precautions for Use

1. Soldering Condition

1.1 (A) Maximum Body Case Temperature Profile for evaluation of Reflow Profile



Note: Reference: IPC/JEDEC J-STD-020D

Preheat

Temperature min (T_{smin}) 150 °C

Temperature max (T_{smax}) 200 °C

Time (Tsmin to Tsmax) (ts) 60-120 seconds

Average ramp-up rate (Tsmax to Tp) 3 °C/second max

Other

Liquidus Temperature (T_L) 217 °C

Time above Liquidus Temperature (t_L) 60-100 sec Peak Temperature (T_P) 260°C

Peak Temperature (T_P) 260° Time within 5 °C of Actual Peak Temperature: T_P - 5°C 30 s

Ramp- Down Rate from Peak Temperature 6°C /second max.

Time 25°C to peak temperature 8 minutes max.

Reflow times 3 times



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